INTEGRATED CIRCUITSPOBIT样工厂, 24小时加

74AVC16836A 20-bit registered driver with inverted register enable and Dynamic Controlled Outputs[™] (3-State)

Product data Supersedes data of 2000 Aug 03

DATA SHEET

2002 Aug 02







Product data

20-bit registered driver with inverted register enable and Dynamic Controlled Outputs[™] (3-State)

74AVC16836A

FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- Complies with JEDEC standard no. 8-1A/5/7.
- CMOS low power consumption
- Input/output tolerant up to 3.6 V
- DCO (Dynamic Controlled Output) circuit dynamically changes output impedance, resulting in noise reduction without speed degradation
- Low inductance multiple V_{CC} and GND pins for minimum noise and ground bounce
- Power off disables 74AVC16836A outputs, permitting Live Insertion
- Integrated input diodes to minimize input overshoot and undershoot
- Full PC133 solution provided when used with PCK2509S or PCK2510S and CBT16292

DESCRIPTION

The 74AVC16836A is a 20-bit universal bus driver. Data flow is controlled by output enable (OE), latch enable (LE) and clock inputs (CP).

This product is designed to have an extremely fast propagation delay and a minimum amount of power consumption.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor (Live Insertion).

A Dynamic Controlled Output (DCO) circuitry is implemented to support termination line drive during transient. See the graphs on page 8 for typical curves.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25 \text{ °C}$; $t_r = t_f \le 2.0 \text{ ns}$; $C_L = 30 \text{ pF}$.

SYMBOL	PARAMETER	CONDITIO	CONDITIONS			
t _{PHL} /t _{PLH}	Propagation delay An to Yn	$V_{CC} = 1.8 V$ $V_{CC} = 2.5 V$ $V_{CC} = 3.3 V$	2.4 1.7 1.5	ns		
t _{PHL} /t _{PLH}	Propagation delay LE to Yn; CP to Yn	V _{CC} = 1.8 V V _{CC} = 2.5 V V _{CC} = 3.3 V	2.7 2.1 1.7	ns		
Cl	Input capacitance					
C			Outputs enabled	25	рЕ	
C _{PD}	Power dissipation capacitance per buffer	VI = GIAD IO ACC.	Output disabled	6	pF	

NOTE:

 C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): 1.

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where: } f_{i} = \text{input frequency in MHz; } C_{L} = \text{output load capacitance in pF;}$ $f_{o} = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) = \text{sum of outputs.}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
56-Pin Plastic 0.5 mm pitch TSSOP	–40 to +85 °C	74AVC16836ADGG	SOT364-1
56-Pin Plastic 0.4 mm pitch TVSOP	–40 to +85 °C	74AVC16836ADGV	SOT481-2

PIN CONFIGURATION

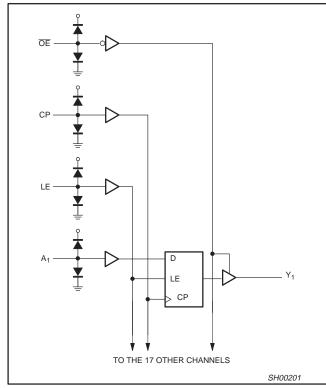
	_				
ŌE	1	56	6	CP	
Y ₀	2	55	5	A ₀	
Y ₁	3	54	Į.	A ₁	
GND	4	53	3	GND	
Y ₂	5	52	2	A ₂	
Y ₃	6	51	ī	A ₃	
V _{CC}	7	50	5	V _{CC}	
Y ₄	8	49	-	A ₄	
Y ₅	9	48	3	A ₅	
Y ₆	10	47	=	A ₆	
GND	11	46	5	GND	
Y ₇	12	45	Ξ.	A ₇	
Y ₈	13	44	-	A ₈	
Y ₉	14	43	4	A ₉	
Y ₁₀	15	42	-	A ₁₀	
Y ₁₁	16	41	Ξ.	A ₁₁	
Y ₁₂	17	40	=	A ₁₂	
GND	18	39	2	GND	
Y ₁₃	19	38	Ξ.	A ₁₃	
Y ₁₄	20	37	-	A ₁₄	
Y ₁₅	20	36	Ξ.	A ₁₅	
	22	35	=		
V _{CC}	22		Ξ.	V _{CC}	
Y ₁₆		34	Ξ.	A ₁₆	
Y ₁₇	24		2	A ₁₇	
GND	25	32	=	GND	
Y ₁₈	26	31	-	A ₁₈	
Y ₁₉	27	30	2	A ₁₉	
NC	28	29	9	LE	SH00159

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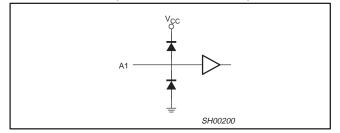
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
28	NC	No connection
2, 3, 5, 6, 8, 9, 10, 12, 13, 14, 15, 16, 17, 19, 20, 21, 23, 24, 26, 27	Y_0 to Y_{19}	Data outputs
4, 11, 18, 25, 32, 35, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage
1	ŌĒ	Output enable input (active LOW)
29	LE	Latch enable input (active LOW)
56	CP	Clock input
55, 54, 52, 51, 49, 48, 47, 45, 44, 43, 42, 41, 40, 38, 37, 36, 34, 33, 31, 30	A_0 to A_{19}	Data inputs

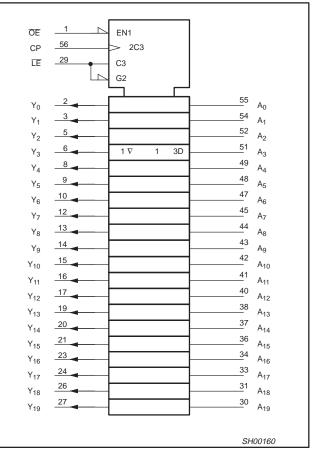
LOGIC SYMBOL



TYPICAL INPUT (DATA OR CONTROL)



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

	INPUTS							
OE	LE	СР	Α	OUTPUTS				
Н	Х	Х	Х	Z				
L	L	Х	L	L				
L	L	Х	Н	Н				
L	Н	\uparrow	L	L				
L	Н	\uparrow	Н	Н				
L	Н	Н	Х	Y ₀ ¹				
L	Н	L	Х	Y ₀ ²				
	NUL							

HIGH voltage level н = L

= LOW voltage level

Don't care =

High impedance "off" state = LOW-to-HIGH level transition =

NOTES:

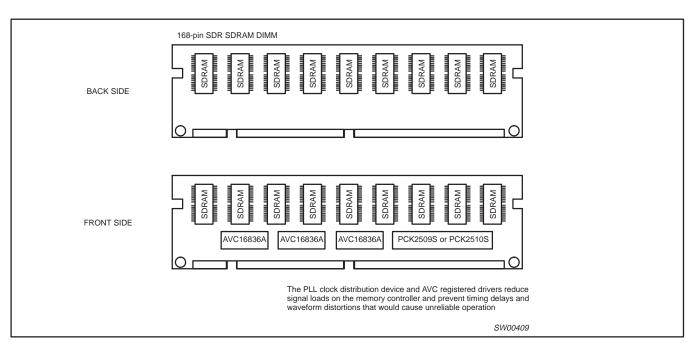
X Z ↑

1. Output level before the indicated steady-state input conditions were established, provided that CP is high before LE goes low.

2. Output level before the indicated steady-state input conditions were established.

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20-bit registered driver with inverted register enable and Dynamic Controlled Outputs[™] (3-State)



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT	
			1.65	1.95		
N N	DC supply voltage (according to JEDEC Low Voltage Standards)		2.3	2.7	V	
V _{CC}			3.0	3.6		
	DC supply voltage (for low voltage applications)		1.2	3.6	V	
VI	DC Input voltage range		0	3.6	V	
V	DC output voltage range; output 3-State		0	3.6	v	
Vo	DC output voltage range; output HIGH or LOW state		0	V _{CC}	v	
T _{amb}	Operating free-air temperature range		-40	+85	°C	
		V_{CC} = 1.65 to 2.3 V	0	30		
t _r , t _f	Input rise and fall times	V _{CC} = 2.3 to 3.0 V	0	20	ns/V	
		V _{CC} = 3.0 to 3.6 V	0	10		

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ <0	-50	mA
VI	DC input voltage	For all inputs ¹	-0.5 to 4.6	V
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	± 50	mA
Vo	DC output voltage; output 3-State	Note 1	-0.5 to 4.6	V
Vo	DC output voltage; output HIGH or LOW state	Note 1	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	± 50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package –plastic thin-medium-shrink (TSSOP)	For temperature range: –40 to +125 °C above +55°C derate linearly with 8 mW/K	600	mW

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

			LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS	Temp	= -40°C to +8	5°C		
			MIN	TYP ¹	MAX	1	
		V _{CC} = 1.2 V	V _{CC}	-	-		
M		V _{CC} = 1.65 to 1.95 V	0.65V _{CC}	0.9	-	V	
VIH	HIGH level Input voltage	V _{CC} = 2.3 to 2.7 V	1.7	1.2	-		
		V _{CC} = 3.0 to 3.6 V	2.0	1.5	-	1	
		V _{CC} = 1.2 V	-	-	GND		
N/		V _{CC} = 1.65 to 1.95 V	-	0.9	0.35V _{CC}	v	
VIL	LOW level Input voltage	V _{CC} = 2.3 to 2.7 V	-	1.2	0.7		
		V _{CC} = 3.0 to 3.6 V	-	1.5	0.8	1	
V _{OH}	HIGH level output voltage	V_{CC} = 1.65 to 3.6 V; V_{I} = V_{IH} or $V_{IL};$ I_{O} = –100 μA	V _{CC} -0.20	V _{CC}	-		
		V_{CC} = 1.65 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -4 mA	V _{CC} -0.45	V _{CC} -0.10	-	V	
0		$V_{CC} = 2.3 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = -8 \text{ mA}$	V _{CC} -0.55	V _{CC} -0.28	-		
		V_{CC} = 3.0 V; V_I = V_{IH} or V_{IL} ; I_O = -12 mA	V _{CC} -0.70	V _{CC} -0.32	-	1	
		V_{CC} = 1.65 to 3.6 V; V_{I} = V_{IH} or $V_{IL};$ I_{O} = 100 μA	-	GND	0.20		
V _{OL}	.OW level output voltage $V_{CC} = 1.65 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = 4 \text{ mA}$		-	0.10	0.45	V	
01		$V_{CC} = 2.3 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = 8 \text{ mA}$	-	0.26	0.55	1	
		V_{CC} = 3.0 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 12 mA	-	0.36	0.70	1	
lį	Input leakage current	$V_{CC} = 3.6 V;$ $V_I = V_{CC} \text{ or GND}$	-	0.1	2.5	μA	
I _{OFF}	3-State output OFF-state current	$V_{CC} = 0 \text{ V}; \text{ V}_{I} \text{ or } \text{ V}_{O} = 3.6 \text{ V}$	-	0.1	±10	μA	
1	2 State output OEE atote ourrest	V_{CC} = 1.65 to 2.7 V; V_{I} = V_{IH} or $V_{IL};$ V_{O} = V_{CC} or GND	-	0.1	5		
I _{OZ}	3-State output OFF-state current	V_{CC} = 3.0 to 3.6 V; V_{I} = V_{IH} or $V_{IL};$ V_{O} = V_{CC} or GND	-	0.1	10	μA	
1		V_{CC} = 1.65 to 2.7 V; V_I = V_{CC} or GND; I_O = 0	-	0.1	20		
ICC	Quiescent supply current	$V_{CC} = 3.0$ to 3.6 V; $V_{I} = V_{CC}$ or GND; $I_{O} = 0$	_	0.2	40	μA	

NOTE:

1. All typical values are at $T_{amb} = 25 \ ^{\circ}C$.

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AC CHARACTERISTICS

GND = 0 V; t_r = t_f \leq 2.0 ns; C_L = 30 pF

		LIMITS													
SYMBOL	PARAMETER WAVEFORM		V_{CC} = 3.3 \pm 0.3 V		V_{CC} = 2.5 \pm 0.2 V		V_{CC} = 1.8 \pm 0.15 V		.15 V	V _{CC} = 1.5 ± 0.1 V		V _{CC} = 1.2 V	UNIT		
			MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	MIN	MAX	TYP	1
	Propagation delay An to Yn	1, 7	0.7	1.5	2.7	0.8	1.7	3.2	1.0	2.4	4.4	2.0	5.3	4.7	ns
t _{PHL} /t _{PLH}	Propagation delay LE to Yn	2, 7	0.7	1.7	3.4	1.0	2.1	3.5	1.5	2.7	5.0	2.0	5.6	5.0	ns
	Propagation delay CP to Yn	3, 7	0.7	1.6	3.0	0.8	1.7	3.2	1.2	2.3	4.1	2.0	4.7	5.7	ns
t _{PZH} /t _{PZL}	3-State output enable time OE to Yn	6, 7	1.0	1.9	3.6	1.0	2.4	4.0	1.5	3.0	5.4	2.5	6.8	6.0	ns
t _{PHZ} /t _{PLZ}	3-State output disable time OE to Yn	6, 7	1.0	2.5	4.8	1.0	2.1	4.7	1.5	3.7	7.5	2.5	7.6	6.6	ns
+	CP pulse width HIGH or LOW	3, 7	1.0	-	-	1.2	-	-	2.0	-	-	-	-	-	ns
t _W	LE pulse width HIGH	2, 7	1.0	-	-	1.2	-	-	2.0	-	-	-	-	-	ns
4	Set-up time An to CP	5, 7	0.2	0	-	0.3	0	-	0.2	0	-	0.3	-	0	ns
ts∪	Set-up time An to LE	4, 7	0.3	0	-	0.6	0.2	-	0.9	0.4	-	1.3	-	1.2	ns
	Hold time An to CP	5, 7	1.2	0.5	-	0.6	0.2	-	0.6	0.2	-	0.6	-	0.1	ns
t _h	Hold time An to LE	4, 7	1.0	0.5	-	0.5	0.1	-	0.4	0	-	0.2	-	-0.7	ns
f _{max}	Maximum clock pulse frequency	3, 7	500	_	-	400	_	-	250	-	-	-	-	_	MHz

NOTE:

1. All typical values are measured at T_{amb} = 25°C and at V_{CC} = 1.8 V, 2.5 V, 3.3 V.

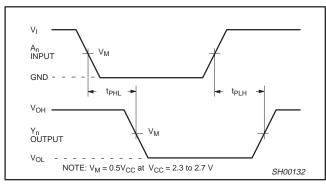
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AC WAVEFORMS FOR V_{CC} = 3.0 V TO 3.6 V RANGE

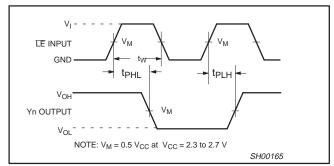
 $\begin{array}{l} V_M = 0.5 \; V_{CC} \\ V_X = V_{OL} + 0.300 \; V \\ V_Y = V_{OH} - 0.300 \; V \\ V_{OL} \; and \; V_{OH} \; are \; the typical output voltage drop that occur with the output load. \\ V_I = V_{CC} \end{array}$

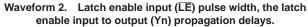
AC WAVEFORMS FOR V_{CC} = 2.3 V TO 2.7 V AND V_{CC} < 2.3 V RANGE

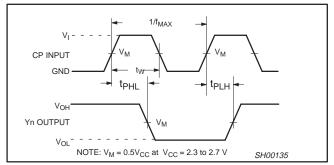
 $\begin{array}{l} V_M = 0.5 \; V_{CC} \\ V_X = V_{OL} + 0.15 \; V \\ V_Y = V_{OH} - 0.15 \; V \\ V_{OL} \; \text{and} \; V_{OH} \; \text{are the typical output voltage drop that occur with the output load.} \\ V_L = V_{CC} \end{array}$



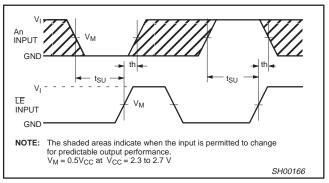
Waveform 1. Input (An) to output (Yn) propagation delay



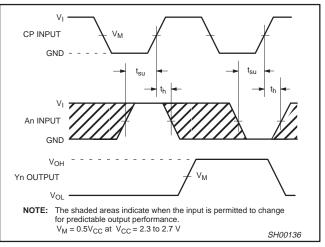




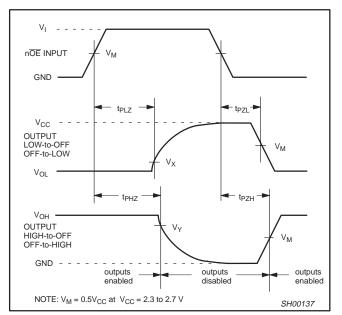
Waveform 3. The clock (CP) to Yn propagation delays, the clock pulse width and the maximum clock frequency.



Waveform 4. Data set-up and hold times for the An input to the $\overline{\text{LE}}$ input



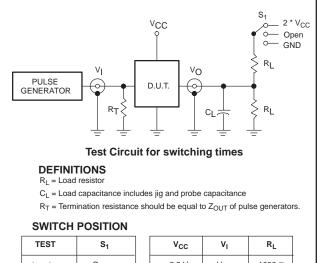
Waveform 5. Data set-up and hold times for the An input to the clock CP input



Waveform 6. 3-State enable and disable times

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TEST CIRCUIT



TEST	S ₁	V _{CC}	v	RL	
t _{PLH} /t _{PHL}	Open	< 2.3 V	V _{CC}	1000 Ω	
t _{PLZ} /t _{PZL}	2 * V _{CC}	2.3–2.7 V	V _{CC}	500 Ω	
t _{PHZ} /t _{PZH}	GND	3.0 V	V _{CC}	500 Ω	
				SV01	018



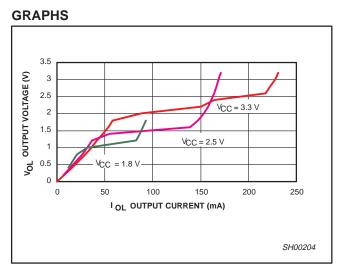


Figure 1. Output voltage (VoL) vs. output current (IoL)

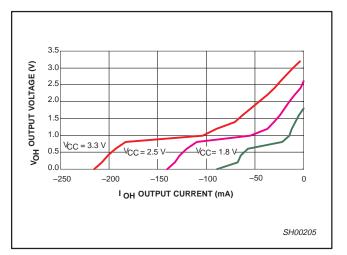
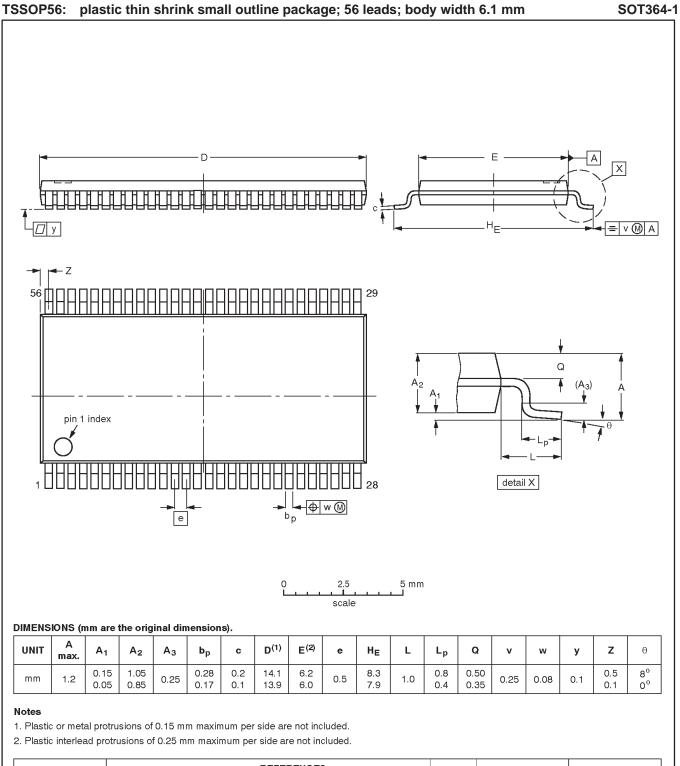


Figure 2. Output voltage (V_{OH}) vs. output current (I_{OH})

A Dynamic Controlled Output (DCO) circuit is designed in. During the transition, it initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figures 1 and 2 show V_{OL} vs. I_{OL} and V_{OH} vs. I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DCO circuit provides a maximum dynamic drive that is equivalent to a high drive standard output device.

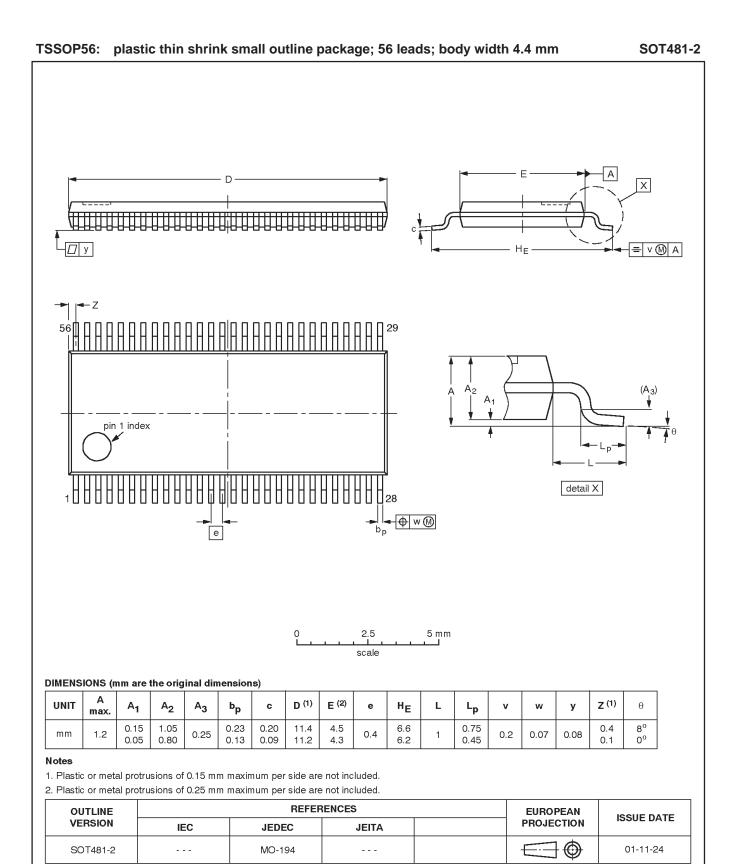
20-bit registered driver with inverted register enable



and Dynamic Controlled Outputs™ (3-State)

REFERENCES OUTLINE EUROPEAN **ISSUE DATE** PROJECTION VERSION IEC JEDEC EIAJ 95-02-10 \odot SOT364-1 MO-153 F 99-12-27

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Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Fax: +31 40 27 24825

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